

HIGH EFFICIENCY RECTIFIER

VOLTAGE RANGE: 70--- 1000 V

CURRENT: 2.0--- 3.5 A

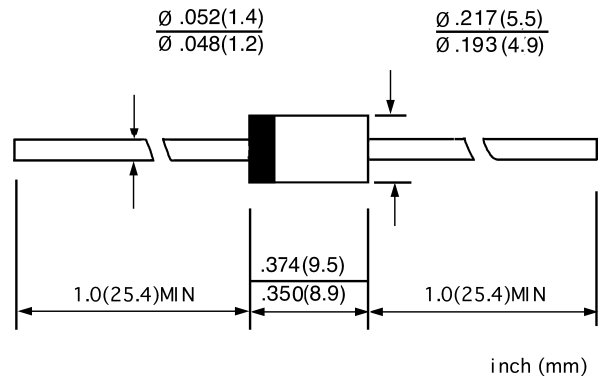
FEATURES

- ◇ Low cost
- ◇ Diffused junction
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with freon, alcohol, Isopropand and similar solvents

MECHANICAL DATA

- ◇ Case: JEDEC DO-27, molded plastic
- ◇ Terminals: Axial leads, solderable per MIL-STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.041 ounces, 1.15grams
- ◇ Mounting: Any

DO - 27



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		RG4Y	RG4Z	RG4	RG4A	RG4C	UNITS
Maximum peak repetitive reverse voltage	V _{RRM}	70	200	400	600	1000	V
Maximum RMS voltage	V _{RMS}	49	140	280	420	700	V
Maximum DC blocking voltage	V _{DC}	70	200	400	600	1000	V
Maximum average forward rectified current 9.5mm lead length, @T _A =75°C	I _{F(AV)}	3.5	3.0		2.0		A
Peak forward surge current 10ms single half-sine-wave superimposed on rated load @T _J =125°C	I _{FSM}	100.0	80.0		50.0	60.0	A
Maximum instantaneous forward voltage @ I _F =I _{F(AV)}	V _F	1.3	1.7	1.8	2.0	3.0	V
Maximum reverse current @T _A =25°C at rated DC blocking voltage @T _A =100°C	I _R	1000.0 5000.0		500.0 2500.0			μ A
Maximum reverse recovery time (Note1)	t _{rr}	50					ns
Typical junction capacitance (Note2)	C _J	70			50		pF
Typical thermal resistance (Note3)	R _{θJL}	8					°C/W
Operating junction temperature range	T _J	- 55 ----- + 150					°C
Storage temperature range	T _{STG}	- 55 ----- + 150					°C

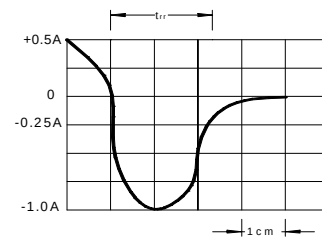
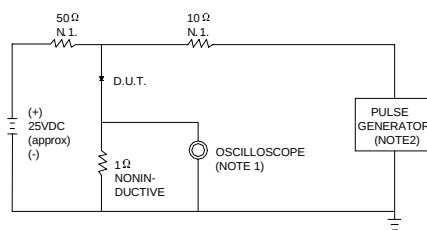
NOTE:1. Measured with $I_F=0.5A$, $I_R=1A$, $t_{rr}=0.25A$.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. Thermal resistance junction to ambient.

www.galaxycn.com

FIG.1 – TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES:1. RISE TIME = 7ns MAX.INPUT IMPEDANCE =1MΩ. 22pF.
2. RISE TIME =10ns MAX.SOURCE IMPEDANCE=50 Ω.

SET TIME BASE FOR 10/20 ns/cm

FIG.2 – TYPICAL FORWARD CHARACTERISTIC

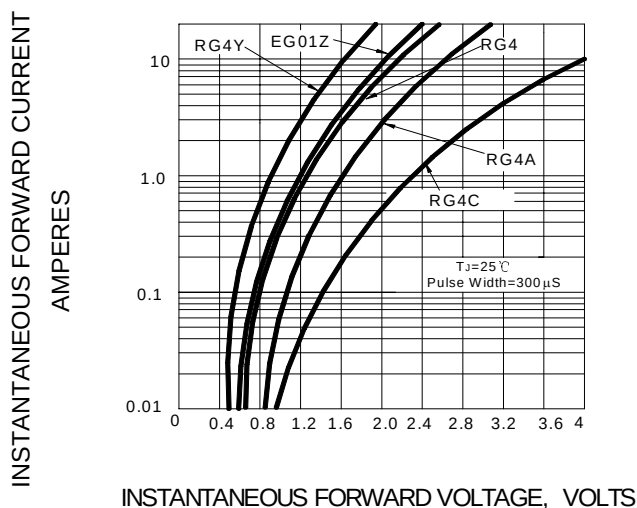


FIG.3 – FORWARD DERATING CURVE

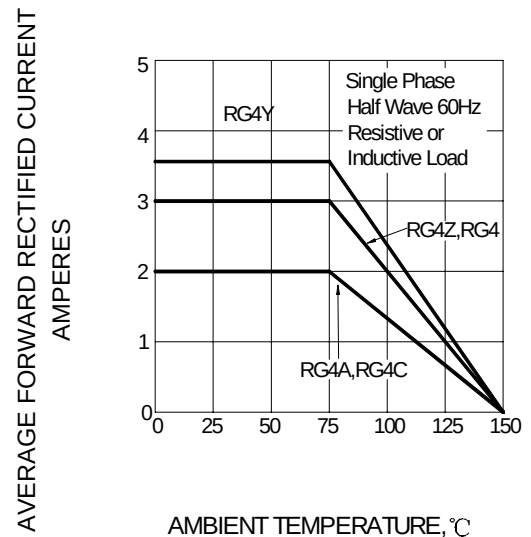


FIG.4 – PEAK FORWARD SURGE CURRENT

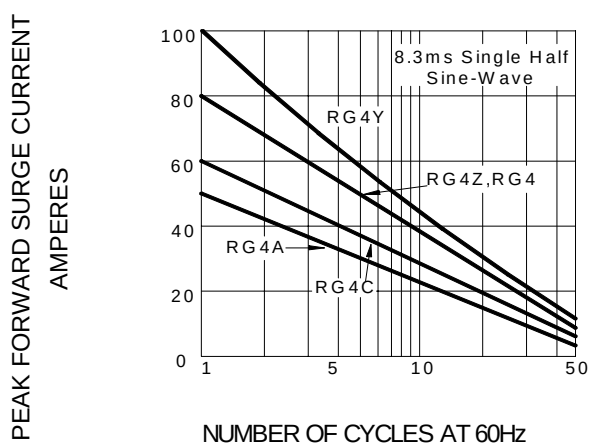


FIG.5--TYPICAL JUNCTION CAPACITANCE

